

LA-UR-

12-00001

Approved for public release;
distribution is unlimited.

Title: INCORPORATION OF DISLOCATION CLIMB IN CRYSTAL PLASTICITY MODELS

Author(s):
A. ALANKAR
R. LEBENSOHN
A. CARO

Intended for: INTERNATIONAL SYMPOSIUM ON PLASTICITY 2012
SAN JAUN, PR
JAN 03 - JAN 8, 2012



Los Alamos National Laboratory, an affirmative action/equal opportunity employer, is operated by the Los Alamos National Security, LLC for the National Nuclear Security Administration of the U.S. Department of Energy under contract DE-AC52-06NA25396. By acceptance of this article, the publisher recognizes that the U.S. Government retains a nonexclusive, royalty-free license to publish or reproduce the published form of this contribution, or to allow others to do so, for U.S. Government purposes. Los Alamos National Laboratory requests that the publisher identify this article as work performed under the auspices of the U.S. Department of Energy. Los Alamos National Laboratory strongly supports academic freedom and a researcher's right to publish; as an institution, however, the Laboratory does not endorse the viewpoint of a publication or guarantee its technical correctness.

Incorporation of dislocation climb in crystal plasticity models

Alankar Alankar, Alfredo Caro and Ricardo Lebensohn

Materials Science and Technology Division, Los Alamos National Laboratory,
MS G755, Los Alamos, NM 87545, USA

This work presents an improved plasticity model for single crystals deforming by a combination of dislocation glide and climb. A constitutive framework based on dislocation densities has been implemented in a viscoplastic self-consistent (VPSC) formulation. Accounting for the explicit evolution of edge and screw dislocations densities enables the instantaneous determination of the climb tensor, which depends on the average character of the mobile dislocations. Mobilities of dislocations accommodating deformation by climb and glide, which depend on their interaction with point defects, are determined using kinetic Monte Carlo simulations.

Incorporation of dislocation climb in crystal plasticity models

Alankar Alankar, Alfredo Caro and Ricardo Lebensohn

Jan. 03, 2012

**Materials Science and Technology Division, Los Alamos National
Laboratory,
MS G755, Los Alamos, NM 87545, USA**

International Symposium on Plasticity 2012 and Its Current Applications,
San Juan, PR,



UNCLASSIFIED

Slide 1

Operated by Los Alamos National Security, LLC for the U.S. Department of Energy's NNSA



Motivation

- Standard crystal plasticity models do not account explicitly for the mechanisms involved in metal deformation in elevated temperatures e.g. phenomena of creep
- In general, these phenomena are modeled via phenomenological description and the models thus developed are not well informed by intrinsic microstructure evolution e.g. dislocation climb
- At high temperatures, the mechanical response of a metal is governed by coupled microstructure activities e.g. creep is accounted by coupled glide and climb of dislocations

• Single crystal plastic deformation geometry (glide only)

Schmid tensor

$$\dot{\epsilon} = \dot{\gamma}_0 \sum_s m^s \left(\frac{|m^s : \sigma'|}{\tau^s} \right)^n \text{sgn}(m^s : \sigma') \text{CRSS}$$

+

Continuum (physically-based) hardening theory

$$\tau^s = \mu b \sqrt{\rho} ; \quad \dot{\rho} = \alpha \sqrt{\rho} - k \rho$$

dislocation density

dislocation density evolution (production, interaction, annihilation)

+

Point defect generation, interaction with dislocations, grain boundaries

Different constitutive formulations for creep rate and their limitations

When the grain size is fairly large, pure metals stressed in the stress range $10^{-5} \mu$ to $10^{-3} \mu$ follow the Power law creep as shown below. $n = 3 - 6$. A is temperature dependent. The equation gives a good fit as shown in the picture. This model assumes that climb occurs to circumvent the obstacles e.g. immobile dislocations in pure metals. Bailey 1930, Norton 1929

$$\dot{\epsilon} = A \sigma^n$$

A is resolved into a constant and temperature dependent part. Q is the activation energy for steady state creep and is almost equal to that of self diffusion. (Dorn 1954). This equation also assumes generation of immobile dislocations.

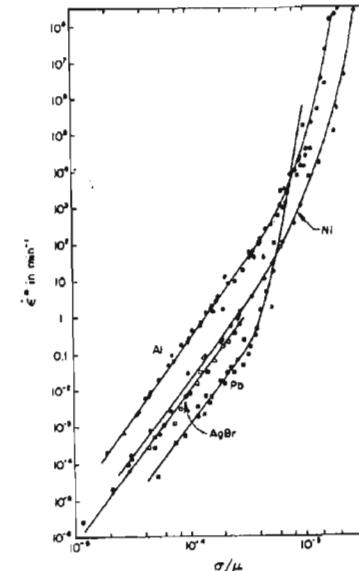
$$\dot{\epsilon} = A \sigma^n \exp(-Q/kT)$$

Weertman, 1955

$$\dot{\epsilon} = A(\sigma^n/kT) \exp(-Q/kT)$$

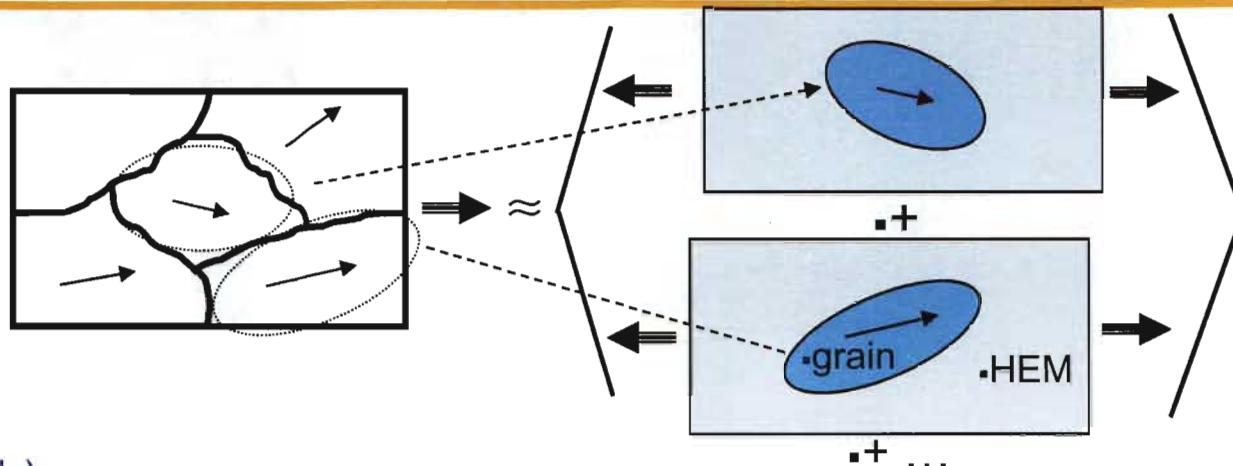
If the production of immobile dislocations is not considered, Weertman 1957. This is proposed for high stresses.

$$\dot{\epsilon} = A \sigma^n \sinh(B \sigma^n/kT) \exp(-Q/kT)^*$$



At higher stress levels than $10^{-3} \mu$ the power law does not predict the creep rates correctly. The experimental observations show a steeper trend. μ is the shear modulus

Self consistent formulation for viscoplastic deformation of polycrystals via glide + climb*



VPSC (glide only):

$$\text{Grain (r): } \dot{\epsilon} = \dot{\gamma}_0 \sum_s m^s \left(\frac{|m^s : \sigma'|}{\tau_0^s} \right)^n \times \text{sgn}(\) \Rightarrow \dot{\epsilon} \underset{\substack{\uparrow \\ \text{linearization}}}{\approx} M^r : \sigma' + \dot{\epsilon}^{\text{or}}$$

HEM: $\dot{E} = M : \Sigma' + \dot{E}^0$

VPSC (climb and glide):

Grain (r):

$$\dot{\epsilon} = \dot{\gamma}_0 \sum_s \left(\frac{|m^s : \sigma'|}{\tau_{0,g}^s} \right)^{n_g} \times \text{sgn}(\) + \left(\frac{|k^{d,s} : \sigma'|}{\tau_{0,c}^s} \right)^{n_c} \times \text{sgn}(\) \Rightarrow \dot{\epsilon} \underset{\substack{\uparrow \\ \text{linearization}}}{\approx} M^r : \sigma' + \dot{\epsilon}^{\text{or}}$$

HEM: $\dot{E} = M : \Sigma' + \dot{E}^0$

Peach-Koehler (P-K) force

$$\mathbf{f} = (\boldsymbol{\sigma} \cdot \mathbf{b}) \times \hat{\mathbf{t}}$$

“Glide” and “climb” components of the P-K force:

$$f_g = [(\boldsymbol{\sigma} \cdot \mathbf{b}) \times \hat{\mathbf{t}}] \cdot \hat{\chi} = (\boldsymbol{\sigma} \cdot \mathbf{b}) \cdot (\hat{\mathbf{t}} \times \hat{\chi}) = |\mathbf{b}| \boldsymbol{\sigma} : (\hat{\mathbf{b}} \otimes \hat{\mathbf{n}}) = |\mathbf{b}| \boldsymbol{\sigma}' : (\hat{\mathbf{b}} \otimes \hat{\mathbf{n}})$$

$$f_c = [(\boldsymbol{\sigma} \cdot \mathbf{b}) \times \hat{\mathbf{t}}] \cdot \hat{\mathbf{n}} = (\boldsymbol{\sigma} \cdot \mathbf{b}) \cdot (\hat{\mathbf{t}} \times \hat{\mathbf{n}}) = -|\mathbf{b}| \boldsymbol{\sigma} : (\hat{\mathbf{b}} \otimes \hat{\chi})$$

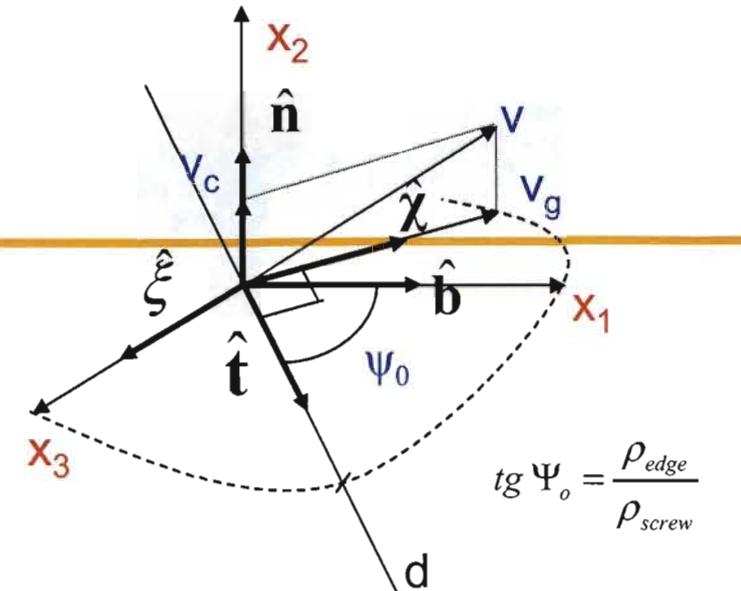
Weertman’s modified expression for the P-K force (*)

$$\mathbf{f} = (\boldsymbol{\sigma}' \cdot \mathbf{b}) \times \hat{\mathbf{t}} + \left[-\frac{k_B T}{\alpha |\mathbf{b}|^3} \log\left(x_v / x_v^{o,PT}\right) \right] \mathbf{b} \times \hat{\mathbf{t}}$$

“Glide” and “climb” components of Weertman- modified P-K force

$$f_g = |\mathbf{b}| \boldsymbol{\sigma}' : (\hat{\mathbf{b}} \otimes \hat{\mathbf{n}})$$

$$f_c = \left[(\boldsymbol{\sigma}' \cdot \mathbf{b}) \times \hat{\mathbf{t}} + \left[-\frac{k_B T}{\alpha |\mathbf{b}|^3} \log\left(x_v / x_v^{o,PT}\right) \right] \mathbf{b} \times \hat{\mathbf{t}} \right] \cdot \hat{\mathbf{n}} = |\mathbf{b}| \boldsymbol{\sigma}' : (\hat{\mathbf{b}} \otimes \hat{\chi}) - |\mathbf{b}| \left[-\frac{k_B T}{\alpha |\mathbf{b}|^3} \log\left(x_v / x_v^{o,PT}\right) \right] (\hat{\mathbf{b}} \otimes \hat{\chi})$$



$$\tan \Psi_o = \frac{\rho_{edge}}{\rho_{screw}}$$

(*) J. Weertman: “The Peach-Koehler Equation for the Force on a Dislocation, Modified for Hydrostatic Pressure”. Phil Mag. 114, 1217 (1964).

UNCLASSIFIED

Geometry of climb

Climb tensor (*): $C_{ij}^s = \chi_i^s b_j^s$ In general $\chi \perp b \Rightarrow C_{kk}^s \neq 0$

Decomposition (*): $C_{ij}^s = k_{ij}^{d,s} + k_{ij}^{h,s} + \kappa_{ij}^s$ (dev + hyd + antisym)

In 'dislocation' coordinates (*): $k_{ij}^{d,s} = \frac{1}{6} \begin{bmatrix} 4 \sin \Psi_0 & 0 & 0 \\ 0 & -2 \sin \Psi_0 & 0 \\ 0 & 0 & -2 \sin \Psi_0 \end{bmatrix}$ $\kappa^s = \frac{1}{2} \begin{bmatrix} 0 & 0 & \cos \Psi_0 \\ 0 & 0 & 0 \\ -\cos \Psi_0 & 0 & 0 \end{bmatrix}$ $k_{ij}^{h,s} = \frac{1}{3} \begin{bmatrix} \sin \Psi_0 & 0 & 0 \\ 0 & \sin \Psi_0 & 0 \\ 0 & 0 & \sin \Psi_0 \end{bmatrix}$

"Climb" P-K force: $f_c = -|\mathbf{b}| \boldsymbol{\sigma}' : (\hat{\mathbf{b}} \otimes \hat{\chi}) - |\mathbf{b}| \left[-\frac{k_B T}{\alpha |\mathbf{b}|^3} \log(x_v / x_v^{o,PT}) \right] (\hat{\mathbf{b}} \otimes \hat{\chi})$

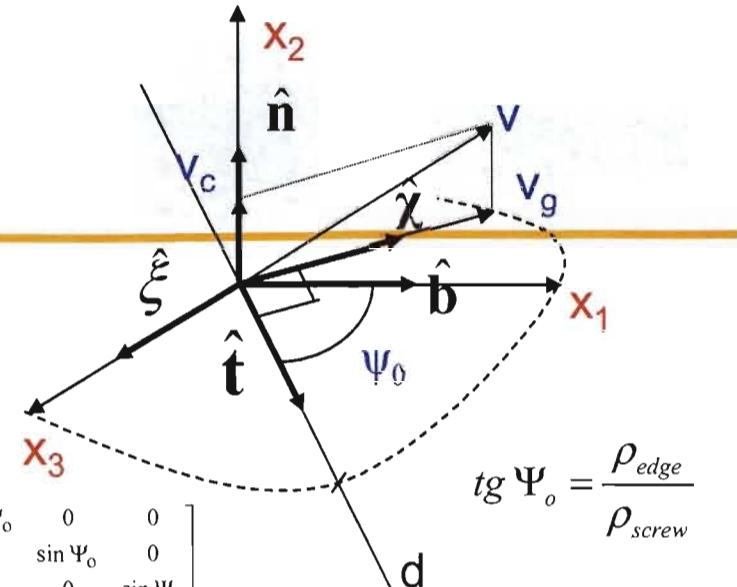
If the local concentration of vacancies is instantaneously restored into the equilibrium concentration:

$$x_v = x_v^{o,PT}, \quad \left| \mathbf{b} \left[-\frac{k_B T}{\alpha |\mathbf{b}|^3} \log(x_v / x_v^{o,PT}) \right] (\hat{\mathbf{b}} \otimes \hat{\chi}) \right| = 0$$

Strain-rate (climb-rate): $\dot{\epsilon}_{ij} = k_{ij}^{d,s} \dot{\beta}^s$

Strain-rate: $\dot{\beta}^s = \dot{\gamma}_o \left(\frac{|k^{d,s} : \boldsymbol{\sigma}'|}{\sigma_{o,c}^s} \right)^{n_c} \times \text{sgn}(k^{d,s} : \boldsymbol{\sigma}')$

Single crystal's strain-rate as a function of stress: $\dot{\epsilon}_{ij} = \dot{\gamma}_o \sum_s k_{ij}^{d,s} \left(\frac{|k^{d,s} : \boldsymbol{\sigma}'|}{\sigma_{o,c}^s} \right)^{n_c} \times \text{sgn}(k^{d,s} : \boldsymbol{\sigma}')$



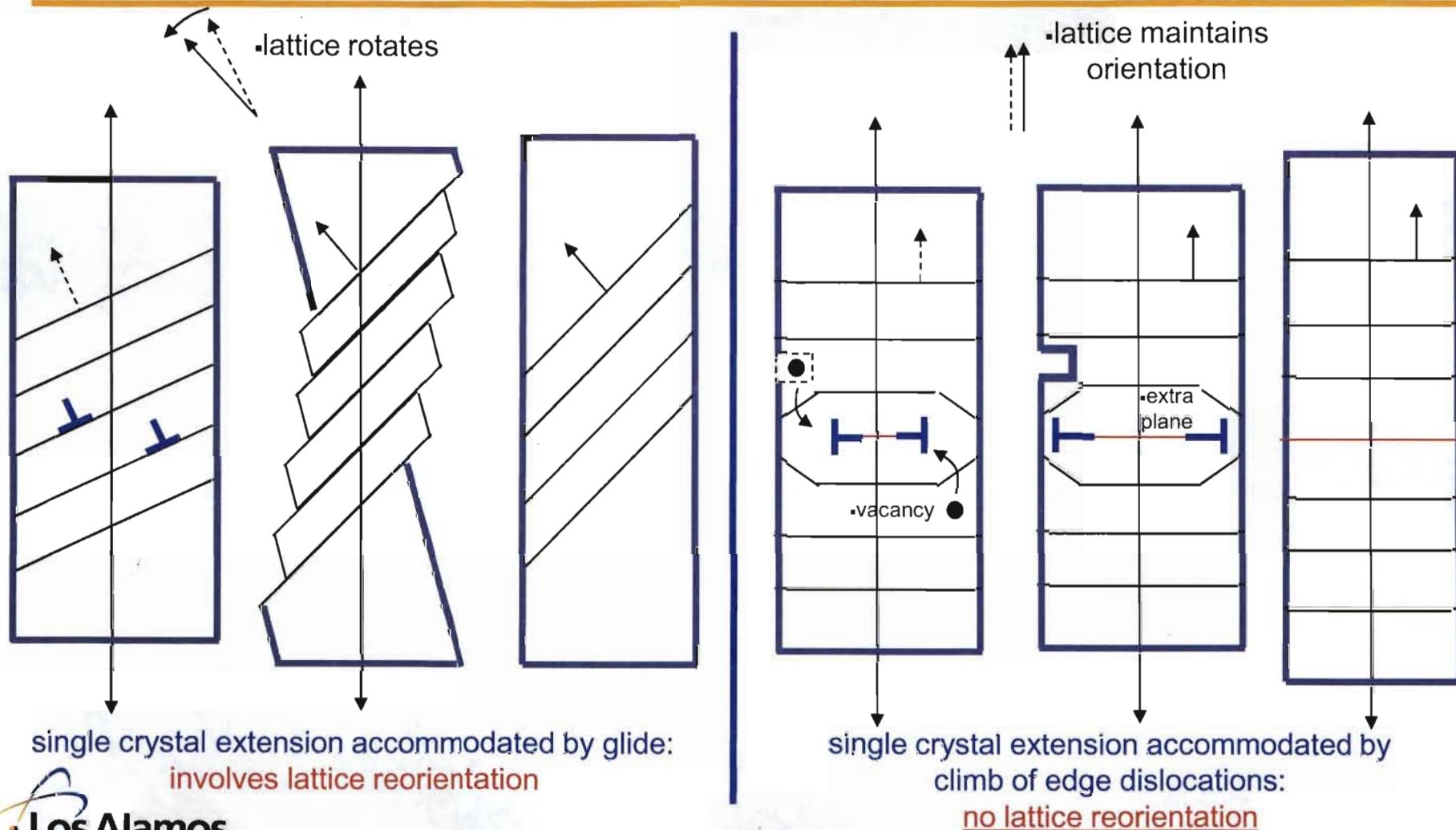
$$\tan \Psi_0 = \frac{\rho_{edge}}{\rho_{screw}}$$

Plastic spin associated with climb:

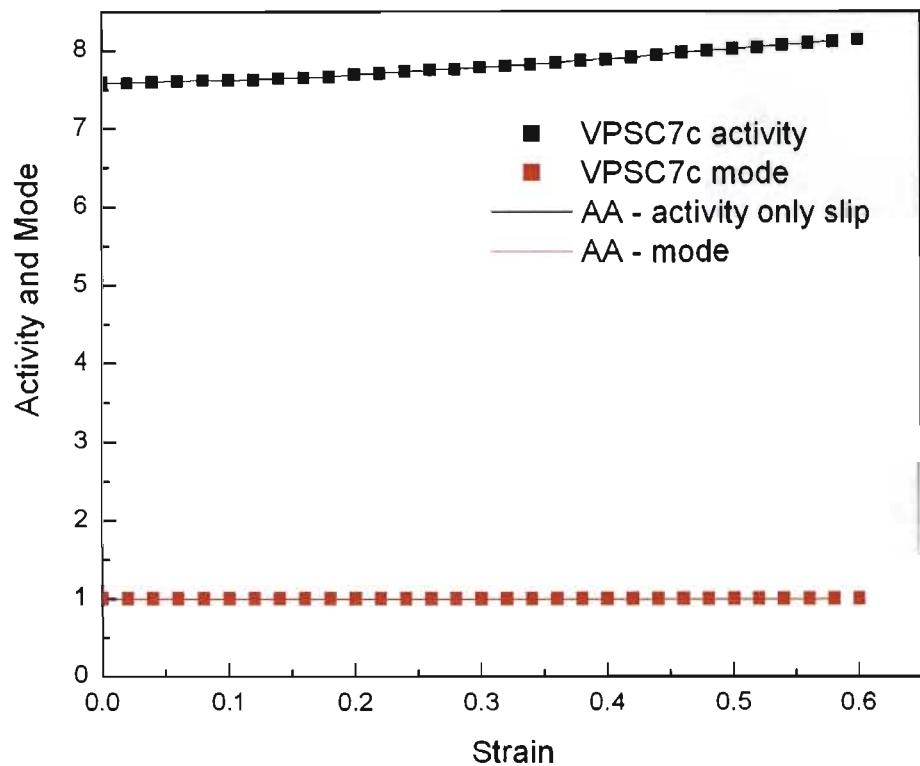
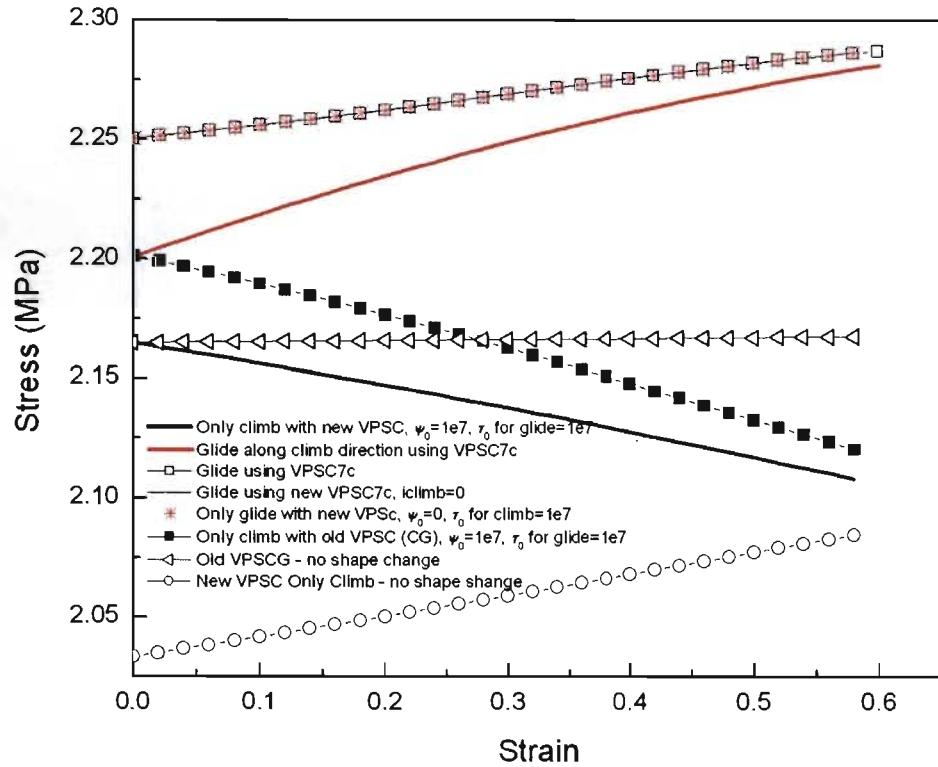
$$\dot{\omega}_{ij}^p = \dot{\gamma}_o \sum_s \kappa_{ij}^s \dot{\beta}^s$$

→ edge dislocations: $\kappa_{ij}^s = 0 \Rightarrow \dot{\omega}_{ij}^p = 0$!

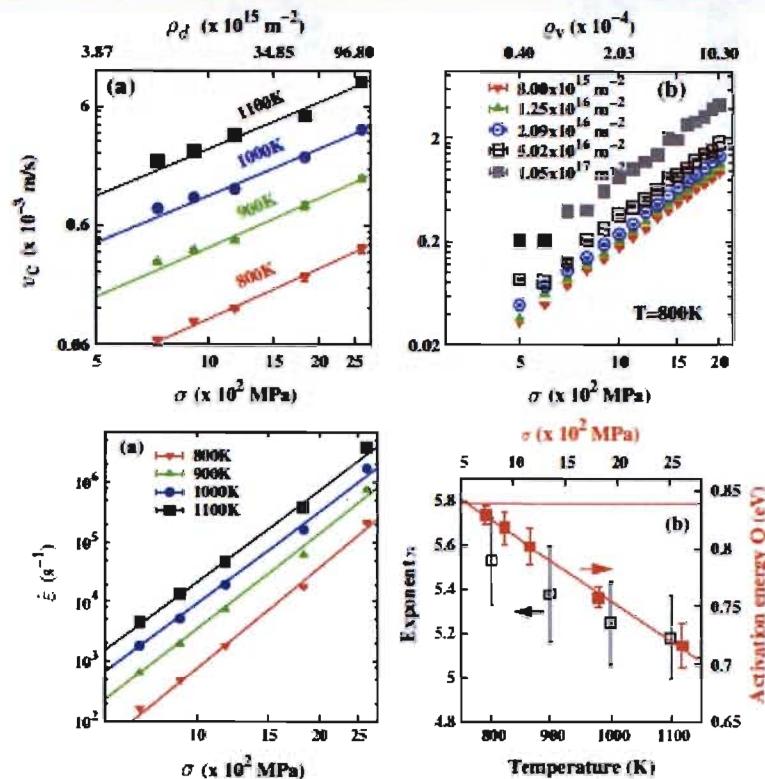
Glide vs. climb in terms of crystal reorientation



Simulations – glide vs. glide + climb



Climb velocity, creep rate and stress exponent – inputs from Kinetic Monte Carlo Simulations



$$\sigma = \alpha u b \sqrt{\rho_d} \quad v_c = kh/N_y$$

$$\dot{\epsilon} = \rho_d b v_c \Leftrightarrow \dot{\epsilon} = A \sigma^n \exp(-Q/k_B T)$$

The values of n given by the above equation for the appropriate stress range is ~ 3 like many other creep models and is lower than as found in the literature, by Cadek and Milicka, Acta Metall., 1969 and Davies et al., Mat. Sci., 1969.

Kabir et al. (2010) were able to achieve n value close to what is determined from experiments but for a $1\text{e}4 - 1\text{e}5$ times higher dislocation density.

The primary reason is that all the models so far consider only climb as the creep governing process. However, it has been suggested that in creep, both glide and climb of dislocations take place.

“almost all of the creep strain is produced by glide motion of dislocations”. J. Weertman, ASM Transactions Quarterly, 61(1968), p. 681

Only climb can take place when glide is disabled to some constraints e.g. geometric constraints. In pure iron, this is not the case.

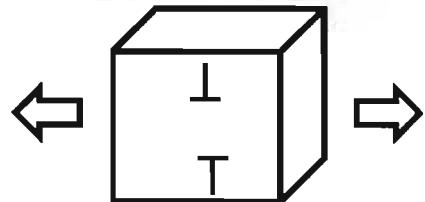
Edelin and Poirier, Phil. Mag., 28 (1973) p.1203

Hafiz et al., Met. Mat. Tran. B., 4(1973) p. 1275

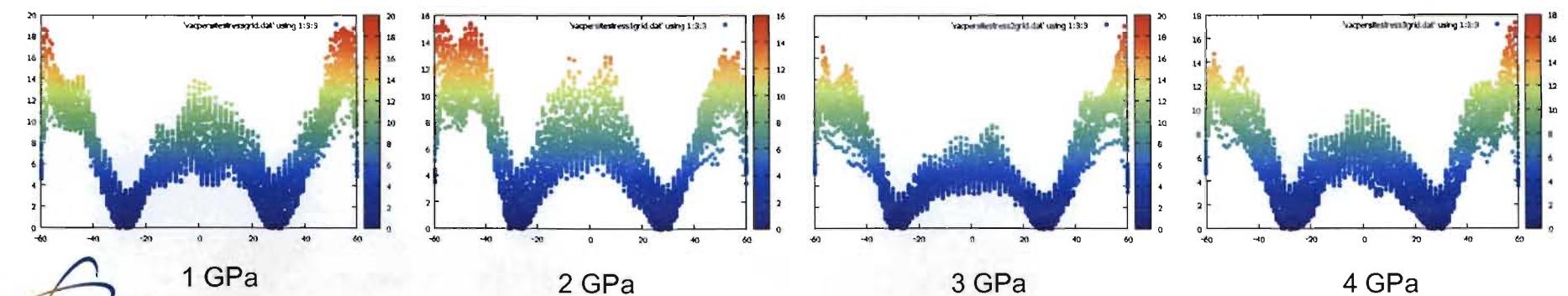
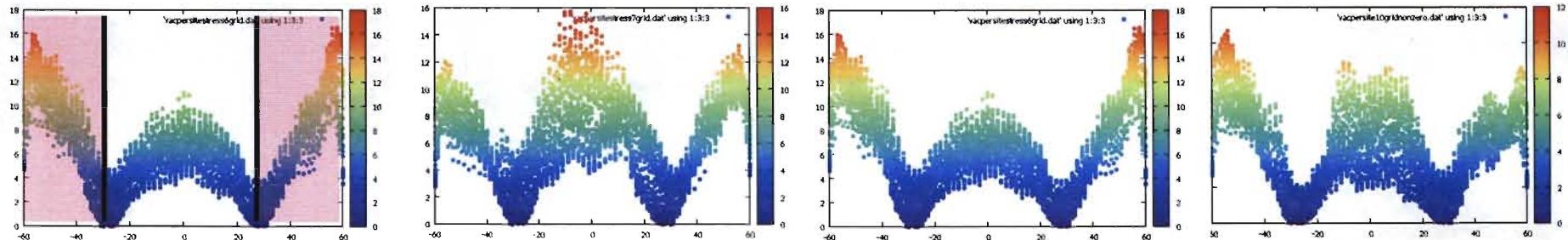
UNCLASSIFIED

Slide 9

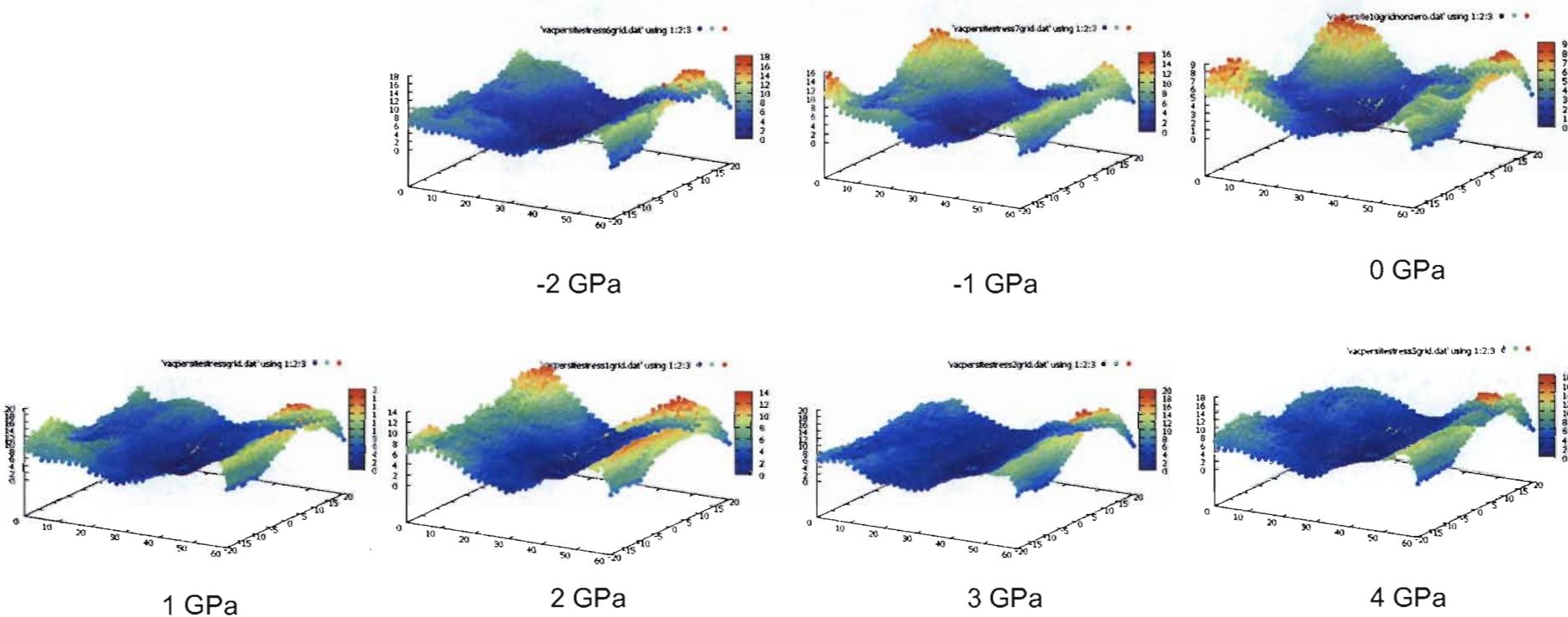
Our calculations of creep rate and stress exponent



$$v_c = kh/N_y \quad \dot{\epsilon} = \rho_d b v_c \quad \dot{\epsilon} = A \sigma^n \exp(-Q/k_B T)$$

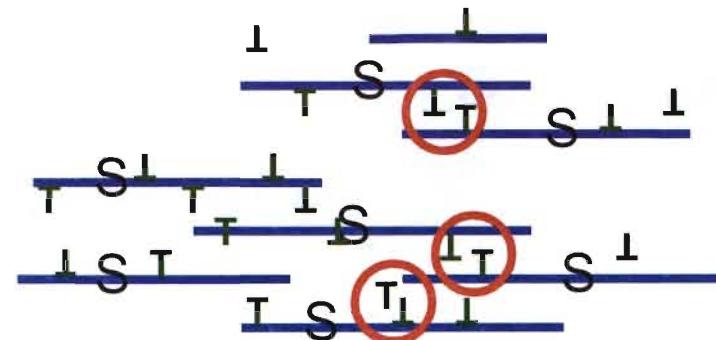
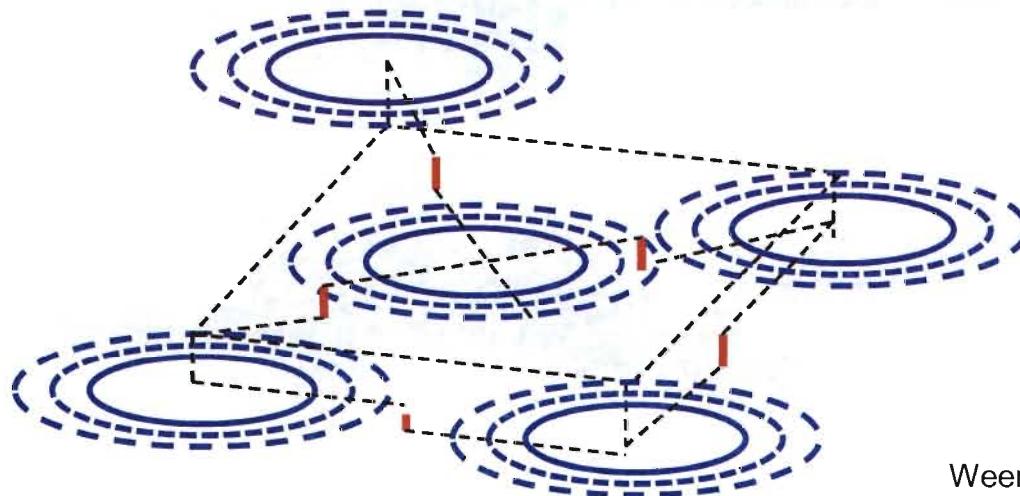


Our calculations of creep rate and stress exponent



$$v_c = kh/N_y \quad \dot{\epsilon} = \rho_d b v_c \quad \dot{\epsilon} = A \sigma^n \exp(-Q/k_B T)$$

Glide accounts for total strain and climb for creep rate



Weertman, 1968

$$\dot{\varepsilon}_{ij}^c = \sum_{s=1}^{N_s} k_{ij}^s \rho^s b v^s = \sum_{s=1}^{N_s} k_{ij}^s \rho^s b [\mu^c (k^s : \sigma^* b)] = \sum_{s=1}^{N_s} k_{ij}^s \rho^s b^2 \mu^c k^s : \sigma^*$$

Plastic strain rate
due to climb

climb mobility
(per unit length) climb force (per
unit length)

Summary

- Connection established between P-K force (glide component) and Schmid law
- Climb component of P-K force used to define "climb" tensor (v.g. Schmid tensor)
- Single-crystal plasticity extended to consider climb-and-glide geometry
- Rate-sensitivity constitutive equation for glide extended to climb
- C+G single-crystal constitutive equation implemented in VPSC for the prediction of polycrystal deformation in the C+G regime
- C+G VPSC model can explain differences in texture evolution in Al deformed at high T and different strain-rates.
- Initial version of the single-crystal C+G model (thermal creep only) assumed vacancy concentration instantaneously restored into the equilibrium concentration (at P and T).
- Single-crystal C+G model (thermal creep) extended beyond the instantaneous restoration of equilibrium concentration of vacancies → requires an adjustable phenomenological parameter, a "chemical" stress due to local non-equilibrium concentration of vacancies.\
- Improved single-crystal C+G model for thermal creep extended to irradiation creep → due to super-saturation of vacancies and interstitials, dislocations can only absorb point-defects to climb → model can consider different sink strengths for vacancies and interstitials and swelling → polarity, analogous to twinning.
- strain = strain(glide), strain rate = climb rate
- Important : glide of dislocations is affected by formation of jogs and that is affecting by vacancy supersaturation
- Also, note that activation energy for vacancy diffusion in iron is different for paramagnetic and ferromagnetic temperature ranges